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Power MOSFET -5.2 A, -30 V

P-Channel SOT-223

Features

- Ultra Low R_{DS(on)}
- Higher Efficiency Extending Battery Life
- Logic Level Gate Drive
- Miniature SOT-223 Surface Mount Package
- Avalanche Energy Specified
- AEC-Q101 Qualified and PPAP Capable NVF5P03T3G
- These Devices are Pb-Free and are RoHS Compliant

Applications

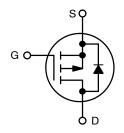
- DC-DC Converters
- Power Management
- Motor Controls
- Inductive Loads
- Replaces MMFT5P03HD



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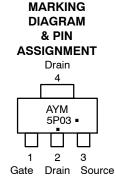
-5.2 AMPERES, -30 VOLTS $R_{DS(on)} = 100 \ m\Omega$



P-Channel MOSFET



SOT-223 CASE 318E STYLE 3



A = Assembly Location

′ = Year

M = Date Code

5P03 = Specific Device Code

= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
NTF5P03T3G	SOT-223 (Pb-Free)	4000 / Tape & Reel
NVF5P03T3G	SOT-223 (Pb-Free)	4000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MAXIMUM RATINGS ($T_J = 25^{\circ}\text{C}$ unless otherwise noted) **Negative sign for P-Channel devices omitted for clarity**

Rating			Max	Unit
Drain-to-Source Voltage			-30	V
Drain-to-Gate Voltage (R _{GS} = 1.0 M Ω)			-30	V
Gate-to-Source Voltage - Continuous			± 20	V
1 sq in FR-4 or G-10 PCB 10 seconds	Thermal Resistance – Junction to Ambient Total Power Dissipation @ T_A = 25°C Linear Derating Factor Drain Current – Continuous @ T_A = 25°C Continuous @ T_A = 70°C Pulsed Drain Current (Note 1)	R _{THJA} PD I _D I _D	40 3.13 25 -5.2 -4.1 -26	°C/W Watts mW/°C A A
Minimum FR-4 or G-10 PCB 10 seconds	Thermal Resistance – Junction to Ambient Total Power Dissipation @ T _A = 25°C Linear Derating Factor Drain Current – Continuous @ T _A = 25°C Continuous @ T _A = 70°C Pulsed Drain Current (Note 1)	R _{THJA} P _D I _D I _D	80 1.56 12.5 -3.7 -2.9 -19	°C/W Watts mW/°C A A A
Operating and Storage	Operating and Storage Temperature Range T _J , T _{stg}		– 55 to 150	°C
Single Pulse Drain–to–Source Avalanche Energy – Starting T_J = 25°C (V_{DD} = -30 Vdc, V_{GS} = -10 Vdc, Peak I_L = -12 Apk, L = 3.5 mH, R_G = 25 Ω)			250	mJ

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

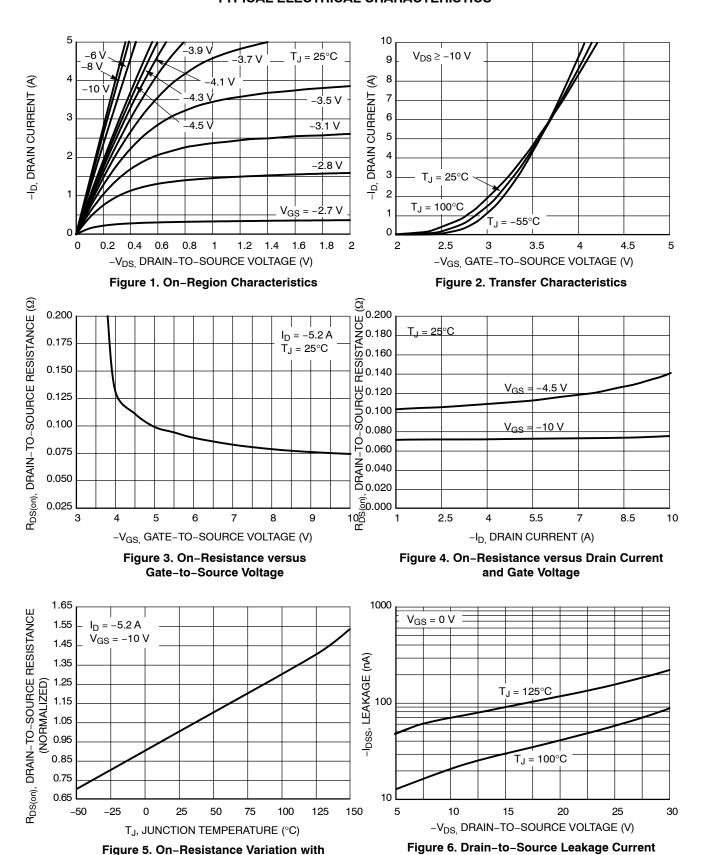
^{1.} Repetitive rating; pulse width limited by maximum junction temperature.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Charac	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS		· L	I	l		1
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}				Vdc	
$(V_{GS} = 0 \text{ Vdc}, I_D = -250 \mu\text{Adc})$ Temperature Coefficient (Positive)		-30 -	- -28	-	mV/°C	
Zero Gate Voltage Drain Current $(V_{DS} = -24 \text{ Vdc}, V_{GS} = 0 \text{ Vdc})$ $(V_{DS} = -24 \text{ Vdc}, V_{GS} = 0 \text{ Vdc}, T_J)$	I _{DSS}	- -	- -	-1.0 -25	μAdc	
Gate-Body Leakage Current (V _{GS} = ± 20 Vdc, V _{DS} = 0 Vdc)	I _{GSS}	-	-	± 100	nAdc	
ON CHARACTERISTICS (Note 2)		I				I
Gate Threshold Voltage (Cpk \geq 2.0) (I $(V_{DS} = V_{GS}, I_D = -250 \mu\text{Adc})$ Threshold Temperature Coefficient (N	V _{GS(th)}	-1.0 -	-1.75 3.5	-3.0 -	Vdc mV/°C	
Static Drain-to-Source On-Resistant ($V_{GS} = -10$ Vdc, $I_D = -5.2$ Adc) ($V_{GS} = -4.5$ Vdc, $I_D = -2.6$ Adc)	R _{DS(on)}	_	76 107	100 150	mΩ	
Forward Transconductance (Note 2) (V _{DS} = -15 Vdc, I _D = -2.0 Adc)	9fs	2.0	3.9	-	Mhos	
DYNAMIC CHARACTERISTICS		'				
Input Capacitance	$(V_{DS} = -25 \text{ Vdc}, V_{GS} = 0 \text{ V},$	C _{iss}	_	500	950	pF
Output Capacitance	f = 1.0 MHz)	C _{oss}	_	153	440	
Transfer Capacitance		C _{rss}	-	58	140	
SWITCHING CHARACTERISTICS	Note 3)	1		•		
Turn-On Delay Time	$(V_{DD} = -15 \text{ Vdc}, I_D = -4.0 \text{ Adc},$	t _{d(on)}	_	10	24	ns
Rise Time	$V_{GS} = -10 \text{ Vdc},$ $R_G = 6.0 \Omega) \text{ (Note 2)}$	t _r	-	33	48	=
Turn-Off Delay Time	- , , ,	t _{d(off)}	-	38	94	
Fall Time		t _f	-	20	92	
Turn-On Delay Time	$(V_{DD} = -15 \text{ Vdc}, I_D = -2.0 \text{ Adc},$	t _{d(on)}	_	16	38	ns
Rise Time	$V_{GS} = -10 \text{ Vdc},$ $R_G = 6.0 \Omega) \text{ (Note 2)}$	t _r	_	45	110	
Turn-Off Delay Time		t _{d(off)}	-	23	60	
Fall Time		t _f	_	24	80	
Gate Charge	$(V_{DS} = -24 \text{ Vdc}, I_D = -4.0 \text{ Adc}, V_{GS} = -10 \text{ Vdc}) \text{ (Note 2)}$	Q_{T}	_	15	38	nC
		Q ₁	_	1.6	_	_
		Q_2	_	3.5	_	
		Q3	_	2.6	-	
SOURCE-DRAIN DIODE CHARA	CTERISTICS					
Forward On-Voltage		V _{SD}	_ _	-1.1 -0.89	-1.5 -	Vdc
Reverse Recovery Time	$(I_S = -4.0 \text{ Adc}, V_{GS} = 0 \text{ Vdc},$	t _{rr}	_	34		ns
	dl _S /dt = 100 A/μs) (Note 2)	ta	_	20	_	
		t _b	_	14	_	
Reverse Recovery Stored Charge	Q _{RR}	-	0.036	-	μC	

2. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%.
3. Switching characteristics are independent of operating junction temperatures.
4. Reflects typical values. $Cpk = \left | \frac{\text{Max limit} - Typ}{3 \times \text{SIGMA}} \right |$

TYPICAL ELECTRICAL CHARACTERISTICS



Temperature

versus Voltage

TYPICAL ELECTRICAL CHARACTERISTICS

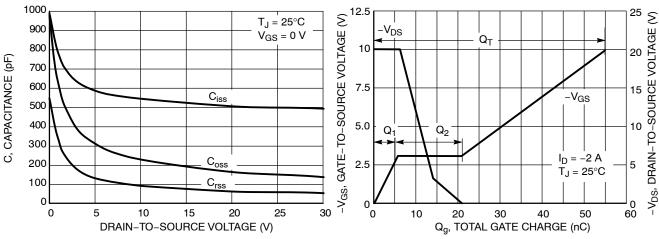


Figure 7. Capacitance Variation

Figure 8. Gate-to-Source and Drain-to-Source Voltage versus Total Charge

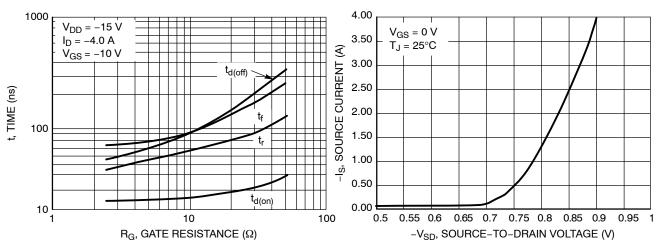


Figure 9. Resistive Switching Time Variation versus Gate Resistance

250

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Figure 10. Diode Forward Voltage versus Current

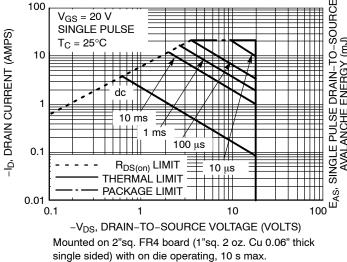


Figure 11. Maximum Rated Forward Biased Safe Operating Area

Figure 12. Maximum Avalanche Energy versus Starting Junction Temperature

TYPICAL ELECTRICAL CHARACTERISTICS

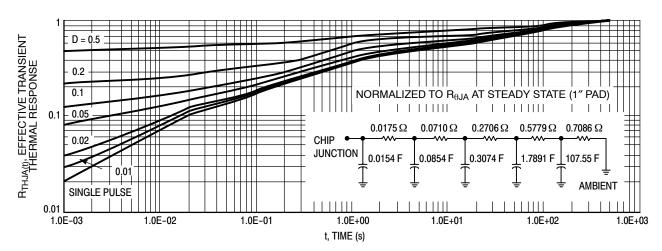
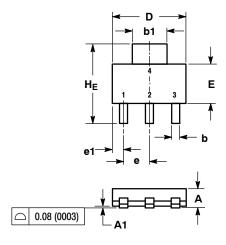
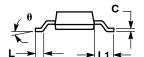


Figure 13. FET Thermal Response

PACKAGE DIMENSIONS

SOT-223 (TO-261) CASE 318E-04 ISSUE N





DIMENSIONING AND TOLERANCING PER ASME Y14.5M,

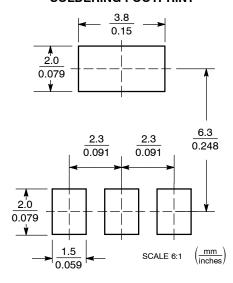
1. DIMENSIONING AND TOLERANCING FER ASME 114.5M,							
1994.							
2 CONTROLLING DIMENSION: INCH							
	MILLIMETERS			INCHES			
DIM	MIN	NOM	MAX	MIN	MOM	MAX	
Α	1.50	1.63	1.75	0.060	0.064	0.068	
A1	0.02	0.06	0.10	0.001	0.002	0.004	
b	0.60	0.75	0.89	0.024	0.030	0.035	
b1	2.90	3.06	3.20	0.115	0.121	0.126	
С	0.24	0.29	0.35	0.009	0.012	0.014	
D	6.30	6.50	6.70	0.249	0.256	0.263	
E	3.30	3.50	3.70	0.130	0.138	0.145	
е	2.20	2.30	2.40	0.087	0.091	0.094	
e1	0.85	0.94	1.05	0.033	0.037	0.041	
L	0.20			0.008			
L1	1.50	1.75	2.00	0.060	0.069	0.078	
HE	6.70	7.00	7.30	0.264	0.276	0.287	
θ	0°	-	10°	0°	_	10°	

STYLE 3: PIN 1. GATE

DRAIN SOURCE

4 DRAIN

SOLDERING FOOTPRINT



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